

Features

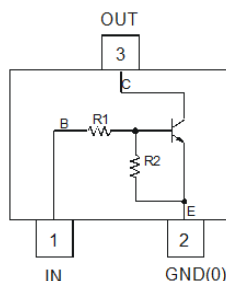
- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDTB)
- Built-In Biasing Resistors
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

P/N	R1 (NOM)	R2 (NOM)
DDTD122LC	0.22k Ω	10k Ω
DDTD142JC	0.47k Ω	10k Ω
DDTD122TC	0.22k Ω	OPEN
DDTD142TC	0.47k Ω	OPEN

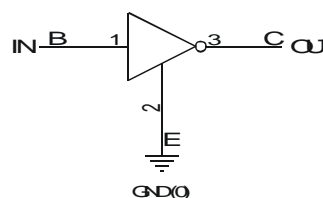
SOT23



Top View



Device Schematic



Equivalent Inverter Circuit

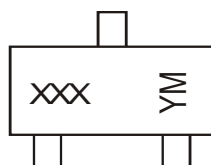
Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DDTD122LC -7-F	AEC-Q101	N75	7	8	3,000
DDTD142JC -7-F	AEC-Q101	N76	7	8	3,000
DDTD122TC -7-F	AEC-Q101	N77	7	8	3,000
DDTD142TC -7-F	AEC-Q101	N78	7	8	3,000

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information

SOT23



XXX = Product Type Marking Code, See Table Above
 YM = Date Code Marking
 Y = Year ex: B = 2014
 M = Month ex: 9 = September

Date Code Key

Year	2014	2015	2016	2017	2018	2019	2020	2021	2022
Code	B	C	D	E	F	G	H	I	J

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Supply Voltage <Pin: (3) to (2)>		V _{CC}	50	V
Input Voltage <Pin: (1) to (2)>	DDTD122LC DDTD142JC	V _{IN}	-5 to +6 -5 to +6	V
Input Voltage <Pin: (2) to (1)>	DDTD122TC DDTD142TC	V _{EBO (MAX)}	5	V
Output Current		I _C	500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		P _D	200	mW
Thermal Resistance, Junction to Ambient Air (Note 5)		R _{θJA}	625	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Note: 5. Mounted on FR4 PC board with recommended pad layout.

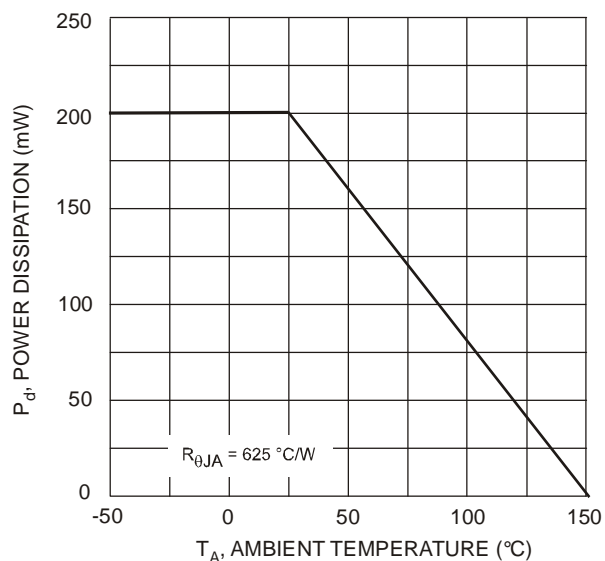


Fig. 1 Power Derating Curve

Electrical Characteristics - R1, R2 Types (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	DDTD122LC DDTD142JC	V _{I(off)}	0.3 0.3	—	—	V	V _{CC} = 5V, I _O = 100μA
	DDTD122LC DDTD142JC	V _{I(on)}	—	—	2.0 2.0	V	V _O = 0.3V, I _O = 20mA V _O = 0.3V, I _O = 20mA
Output Voltage		V _{O(on)}	—	—	0.3V	V	I _O /I _I = 50mA/2.5mA
Input Current	DDTD122LC DDTD142JC	I _I	—	—	28 13	mA	V _I = 5V
Output Current		I _{O(off)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	DDTD122LC DDTD142JC	G _I	56 56	—	—	—	V _O = 5V, I _O = 50mA
Gain-Bandwidth Product (Note 6)		f _T	—	200	—	MHz	V _{CE} = 10V, I _E = 5mA, f = 100MHz

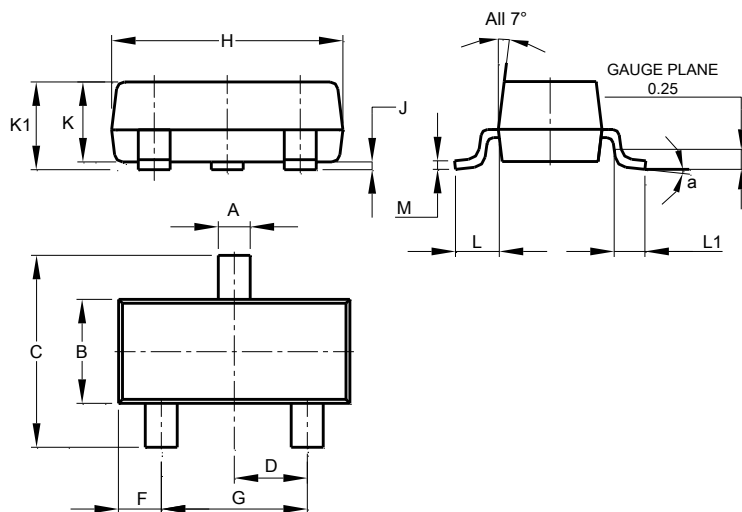
Electrical Characteristics - R1- Only, R2- Only Types (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV _{CBO}	50	—	—	V	I _C = 50μA
Collector-Emitter Breakdown Voltage		BV _{CEO}	40	—	—	V	I _C = 1mA
Emitter-Base Breakdown Voltage	DDTD122TC DDTD142TC	BV _{EBO}	5	—	—	V	I _E = 50μA I _E = 50μA
Collector Cut-Off Current		I _{CBO}	—	—	0.5	μA	V _{CB} = 50V
Emitter Cut-Off Current	DDTD122TC DDTD142TC	I _{EBO}	— —	—	0.5 0.5	μA	V _{EB} = 4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	—	—	0.3	V	I _C = 50mA, I _B = 2.5mA
DC Current Transfer Ratio	DDTD122TC DDTD142TC	h _{FE}	100 100	250 250	600 600	—	I _C = 5mA, V _{CE} = 5V
Gain-Bandwidth Product (Note 6)		f _T	—	200	—	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz

Note: 6. Transistor – For Reference Only

Package Outline Dimensions

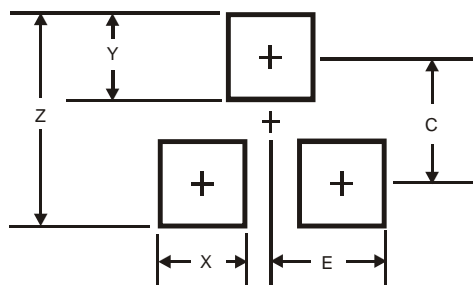
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.890	1.00	0.975
K1	0.903	1.10	1.025
L	0.45	0.61	0.55
L1	0.25	0.55	0.40
M	0.085	0.150	0.110
a	8°		
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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